

Jihee Jeon

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	Formation of ultra-low resistance contact with nickel stanogermanide/heavily doped n - $\text{Ge}_{1-x}\text{Sn}_x$ structure. Semiconductor Science and Technology, 2018, 33, 124001.	2.0	9
2	Growth and electrical properties of in situ Sb-doped $\text{Ge}_{1-x}\text{Sn}_x$ epitaxial layers for source/drain stressor of strained-Ge transistors. Japanese Journal of Applied Physics, 2018, 57, 121303.	1.5	4
3	Saturation of electrically activated Sb concentration in heavily Sb-doped n - $\text{Ge}_{1-x}\text{Sn}_x$ epitaxial layers. Japanese Journal of Applied Physics, 2020, 59, SLLF02.	1.5	3
4	Photoluminescence properties of heavily Sb doped $\text{Ge}_{1-x}\text{Sn}_x$ and heterostructure design favorable for n - $\text{Ge}_{1-x}\text{Sn}_x$ active layer. Japanese Journal of Applied Physics, 2022, 61, SA1004.	1.5	1
5	Development of in-situ Sb-Doped $\text{Ge}_{1-x}\text{Sn}_x$ Epitaxial Layers for Source/Drain Stressor of Strained Ge Transistors. , 2017, , .		0